

Product Change Notification / SYST-23BFZM094

Date:

28-Mar-2023

Product Category:

Automotive LED Drivers

PCN Type:

Document Change

Notification Subject:

Data Sheet - AT9919 Hysteretic Buck High-Brightness LED Driver with High-Side Current Sensing Data Sheet

Affected CPNs:

SYST-23BFZM094_Affected_CPN_03282023.pdf SYST-23BFZM094_Affected_CPN_03282023.csv

Notification Text:

SYST-23BFZM094

Microchip has released a new Datasheet for the AT9919 Hysteretic Buck High-Brightness LED Driver with High-Side Current Sensing Data Sheet of devices. If you are using one of these devices please read the document located at AT9919 Hysteretic Buck High-Brightness LED Driver with High-Side Current Sensing Data Sheet.

Notification Status: Final

Description of Change: Added information about the automotive qualification status of the device in Section "Features". • Updated Section 4.1 "Package Marking Information". • Modified package type from 8-Lead DFN to 8-Lead WDFN. • Updated Section "Product Identification System", with Automotive Qualified devices. • Minor text and format changes throughout.

Impacts to Data Sheet: See above details.

Reason for Change: To Improve Productivity

Change Implementation Status: Complete

Date Document Changes Effective: 28 March 2023

NOTE: Please be advised that this is a change to the document only the product has not been changed.

Markings to Distinguish Revised from Unrevised Devices::N/A

Attachments:

AT9919 Hysteretic Buck High-Brightness LED Driver with High-Side Current Sensing Data Sheet

Please contact your local Microchip sales office with questions or concerns regarding this notification.

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Affected Catalog Part Numbers (CPN)

AT9919K7-G AT9919K7-GVAO



AT9919

Hysteretic Buck High-Brightness LED Driver with High-Side Current Sensing

Features

- AEC-Q100 Qualified
- Hysteretic Control with High-side Current Sensing
- Wide Input Voltage Range: 4.5V to 40V
- >90% Efficiency
- Typical ±5% LED Current Accuracy
- Up to 2 MHz Switching Frequency
- Adjustable Constant LED Current
- Analog or Pulse-Width Modulation (PWM) Control Signal for PWM Dimming
- Overtemperature Protection
- –40°C to +125°C Operating Temperature Range

Applications

- LED Lighting Applications
- · Automotive Applications

General Description

AT9919 is a PWM controller IC designed to drive high-brightness LEDs using a buck topology. It operates from an input voltage of 4.5 VDC to 40 VDC and employs hysteretic control with a high-side current sense resistor to set the constant output current.

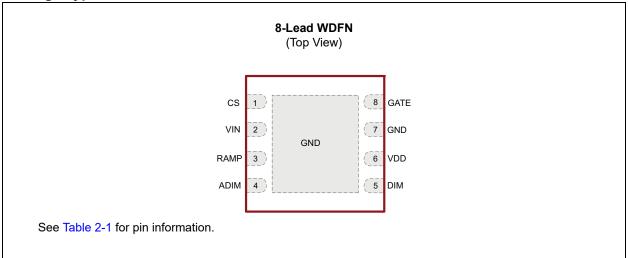
The operating frequency range can be set by selecting the proper inductor. Operation at high switching frequency is possible since the hysteretic control maintains accuracy even at high frequencies. This permits the use of small inductors and capacitors, minimizing space and cost in the overall system.

LED brightness control is achieved with PWM dimming from an analog or PWM input signal. Unique PWM circuitry allows true constant color with a high dimming range. The dimming frequency is programmed using a single external capacitor.

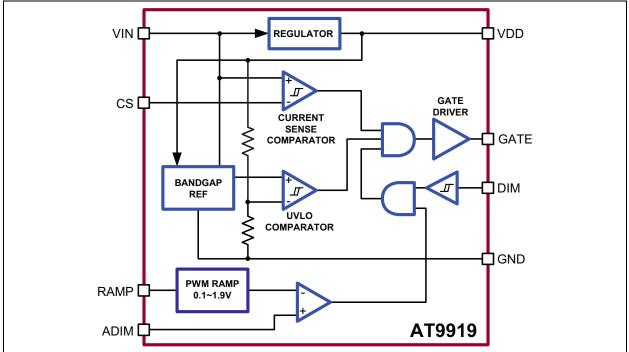
AT9919 comes in a small, 8-Lead WDFN package and is qualified for LED lighting applications.

AT9919 passes the automotive AEC-Q100 reliability testing.

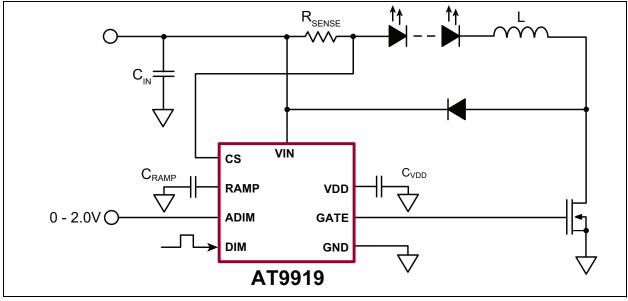
Package Type



Functional Block Diagram



Typical Application Circuit



1.0 ELECTRICAL CHARACTERISTICS

Absolute Maximum Ratings†

V _{IN} and CS to GND	0.3V to +45V
V _{DD} , GATE, RAMP, DIM, ADIM to GND	-0.3V to +6V
CS to V _{IN}	
Operating Temperature Range	
Junction Temperature	150°C
Storage Temperature Range	65°C to 150°C
Continuous Power Dissipation (T _A = +25°C)	1.6W

† Notice: Stresses above those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress rating only, and functional operation of the device at those or any other conditions above those indicated in the operational sections of this specification is not intended. Exposure to maximum rating conditions for extended periods may affect device reliability.

ELECTRICAL CHARACTERISTICS

Electrical Specifications: $V_{IN} = 12V$, $V_{DIM} = V_{DD}$, $V_{RAMP} = GND$, $C_{VDD} = 1 \ \mu\text{F}$, $R_{SENSE} = 0.5\Omega$, $T_A = T_J = -40^{\circ}\text{C}$ to +125°C (Note 1) unless otherwise noted.

Parameter	Sym.	Min.	Тур.	Max.	Unit	Conditions			
Input DC Supply Voltage Range	V _{IN}	4.5		40	V	DC input voltage			
Internally Regulated Voltage	V _{DD}	4.5		5.5	V	V _{IN} = 6V to 40V			
Supply Current	I _{IN}	_		1.5	mA	GATE open			
Shutdown Supply Current	I _{IN, SDN}			900	μA	DIM < 0.7V			
Current Limit			30		mA	V _{IN} = 4.5V, V _{DD} = 0V			
	I _{IN, LIM}		8			V _{IN} = 4.5V, V _{DD} = 4V			
Oscillator Frequency	f _{OSC}			2	MHz				
V _{DD} Undervoltage Lockout Threshold	UVLO		_	4.5	V	V _{DD} rising			
V _{DD} Undervoltage Lockout Hysteresis	UVLO _{HYST}		500	_	mV	V _{DD} falling			
SENSE COMPARATOR									
Sense Voltage Threshold High	V _{CS(HI)}	198	230	257	mV	$(V_{IN} - V_{CS})$ rising			
Sense Voltage Threshold Low	V _{CS(LO)}	147	170	195	mV	$(V_{IN} - V_{CS})$ falling			
Average Reference Voltage	V _{CS(AVG)}	186	200	214	mV	$V_{CS(AVG)} = 0.5V_{CS(HI)} + 0.5V_{CS(LO)}$			
Propagation Delay to Output High	t _{DPDH}		70	_	ns	Falling edge of V _{IN} – V _{CS} = V _{RS(LO)} – 70 mV			
Propagation Delay to Output Low	t _{DPDL}		70		ns	Rising edge of V _{IN} – V _{CS} = V _{RS(HI)} + 70 mV			
Current Sense Input Current	I _{CS}	_	—	1	μA	$V_{IN} - V_{CS} = 200 \text{ mV}$			
Current Sense Threshold Hysteresis	V _{CS(HYST)}		56	80	mV				
DIM INPUT									
Pin DIM Input High Voltage	V _{IH}	2.2	—	—	V				
Pin DIM Input Low Voltage	V _{IL}	_	—	0.7	V				
Turn-on Time	t _{ON}		100	_	ns	DIM rising edge to V _{GATE} = 0.5 x V _{DD} , C _{GATE} = 2 nF			
Turn-off Time	t _{OFF}		100	_	ns	DIM falling edge to V _{GATE} = 0.5 x V _{DD} , C _{GATE} = 2 nF			

Note 1: Limits obtained by design and characterization.

2: For design guidance only

ELECTRICAL CHARACTERISTICS (CONTINUED)

Electrical Specifications: $V_{IN} = 12V$, $V_{DIM} = V_{DD}$, $V_{RAMP} = GND$, $C_{VDD} = 1 \ \mu\text{F}$, $R_{SENSE} = 0.5\Omega$, $T_A = T_J = -40^{\circ}\text{C}$ to +125°C (Note 1) unless otherwise noted.

Parameter Sym. Min. Typ. Max. Unit Conditions									
	Cynn.		יאָני.	Wax.	Unit	Conditions			
GATE DRIVER									
GATE Current, Source	L	0.3	0.5		А	V _{GATE} = GND (Note 2)			
GATE Current, Sink	I _{GATE}	0.7	1	—	А	V _{GATE} = V _{DD} (Note 2)			
GATE Output Rise Time	T _{RISE}	_	40	55	ns	C _{GATE} = 2 nF			
GATE Output Fall Time	T _{FALL}	_	17	25	ns	C _{GATE} = 2 nF			
GATE High Output Voltage	V _{GATE(HI)}	$V_{DD} - 0.5$		_	V	I _{GATE} = 10 mA			
GATE Low Output Voltage	V _{GATE(LO)}	_	_	0.5	V	I _{GATE} = –10 mA			
OVERTEMPERATURE PROTEC	TION								
Over Temperature Trip Limit	т _{от}	128	140	—	°C	Note 2			
Temperature Hysteresis	ΔT_{HYST}	—	60	—	°C	Note 2			
ANALOG CONTROL OF PWM D	IMMING								
	f	130	—	300	Hz	C _{RAMP} = 47 nF			
Dimming Frequency	f _{RAMP}	550	—	1250	112	C _{RAMP} = 10 nF			
RAMP Threshold, Low	V _{LOW}	_	0.1	_	V				
RAMP Threshold, High	V _{HIGH}	1.8	_	2.1	V				
ADIM Offset Voltage	V _{OS}	-35	_	+35	mV				

Note 1: Limits obtained by design and characterization.

2: For design guidance only

TEMPERATURE SPECIFICATIONS

Parameter	Sym.	Min.	Тур.	Max.	Unit	Conditions		
TEMPERATURE RANGE								
Operating Temperature	T _A	-40		+125	°C			
Junction Temperature	Τ _J	_		+150	°C			
Storage Temperature	Τ _S	-65		+150	°C			
PACKAGE THERMAL RESISTANCE								
8-Lead WDFN	θ_{JA}		+37	_	°C/W			

2.0 PIN DESCRIPTION

The details on the pins of AT9919 are listed on Table 2-1. Refer to **Package Type** for the location of pins.

	-	-					
Pin Number	Pin Name	Description					
1	CS	Current sense input. Senses LED string current.					
2	VIN	Input voltage 4.5V to 40V DC.					
3	RAMP	Analog PWM dimming ramp output.					
4	ADIM	Analog input signal, 0V~2V, for PWM Dimming control.					
5	DIM	PWM Dimming input signal					
6	VDD	Internally regulated supply voltage. Connect a capacitor from VDD to ground.					
7	GND	Device ground.					
8	GATE	Drives GATE of the external MOSFET.					
TAB	GND	Must be wired to pin 7 on PCB.					

TABLE 2-1: PIN FUNCTION TABLE

3.0 APPLICATION INFORMATION

3.1 General Description

AT9919 is а step-down constant-current high-brightness LED (HB LED) driver. The device operates from a 4.5V to 40V input voltage range and provides the gate driver output to an external N-channel MOSFET. A high-side current sense resistor sets the output current and a dedicated PWM dimming input (DIM) allows for a wide range of dimming duty ratios. The PWM dimming could also be achieved by applying a DC voltage between 0V and 2V to the analog dimming input (ADIM). In this case, the dimming frequency can be programmed using a single capacitor at the RAMP pin. The high-side current sensing scheme minimizes the number of external components while delivering LED current with a ±8% accuracy, using a 1% sense resistor.

3.2 Undervoltage Lockout (UVLO)

AT9919 includes a 3.7V UVLO with a typical 500 mV hysteresis. When V_{IN} falls below 3.7V, GATE goes low, turning off the external N-channel MOSFET. GATE goes high once V_{IN} is 4.5V or higher.

3.3 5V Regulator

 V_{DD} is the output of a 5V regulator capable of sourcing 8 mA. Bypass V_{DD} to GND with a 1 µF capacitor.

3.4 DIM Input

AT9919 allows dimming with a PWM signal at the DIM input. A logic level below 0.7V at DIM forces the $GATE_{OUTPUT}$ low, turning off the LED current. To turn on the LED current, the logic level at DIM must be at least 2.2V.

3.5 ADIM and RAMP Inputs

The PWM dimming scheme can also be implemented by applying an analog control signal to the ADIM pin. If an analog control signal of 0V~2.0V is applied to ADIM, the device compares this analog input to a voltage ramp to pulse width modulate the LED current. Connecting an external capacitor to RAMP programs the PWM dimming ramp frequency. See Equation 3-1.

EQUATION 3-1:

$$f_{PWM} = \frac{1}{C_{RAMP} \times 120k\Omega}$$

The DIM and ADIM inputs can be used simultaneously. In such case, a $f_{PWM(MAX)}$ lower than the frequency of the dimming signal at DIM must be selected. The smaller dimming duty cycle of ADIM and DIM will determine the GATE signal.

When the analog control of PWM dimming feature is not used, RAMP must be wired to GND and ADIM should be connected to V_{DD} .

One possible application of the ADIM feature may include protection of the LED load from overtemperature by connecting an NTC thermistor to ADIM as shown in Figure 3-1.

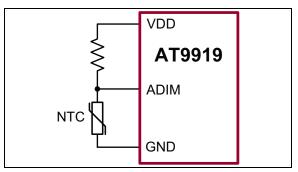


FIGURE 3-1: Overtemperature Protection using ADIM Pin.

3.6 Setting LED Current with the External Resistor (R_{SENSE})

The output current in the LED is determined by the external current sense resistor (R_{SENSE}) connected between V_{IN} and CS. Disregarding the effect of the propagation delays, the sense resistor can be calculated as seen in Equation 3-2.

EQUATION 3-2:

$$R_{SENSE} \approx \left(\frac{1}{2}\right) \times \left(\frac{V_{RS(HI)} + V_{RS(LO)}}{I_{LED}}\right) = \frac{200 mV}{I_{LED}}$$

3.7 Selecting Buck Inductor (L)

AT9919 regulates the LED output current using an input comparator with hysteresis. (See Figure 3-2.) As the current through the inductor ramps up and the voltage across the sense resistor reaches the upper threshold, the voltage at GATE goes low, turning off the external MOSFET. The MOSFET turns on again when the inductor current ramps down through the freewheeling diode until the voltage across the sense resistor equals the lower threshold.

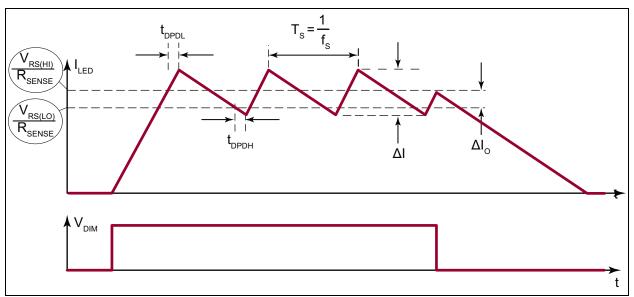


FIGURE 3-2: Inductor Current Waveform.

Equation 3-3 shows how to determine the inductor value for a desired operating frequency (f_S) .

EQUATION 3-3:

$$L = \frac{(V_{IN} - V_{OUT}) \times V_{OUT}}{f_S V_{IN} \Delta I_O} - \frac{(V_{IN} - V_{OUT}) \times t_{DPDL}}{\Delta I_O} - \frac{V_{OUT} t_{DPDH}}{\Delta I_O}$$

Where:
$$\Delta I_O = \frac{V_{RS(HI)} - V_{RS(LO)}}{R_{SENSE}}$$

and t_{DPDL} and t_{DPDH} are the propagation delays. Note that the current ripple (ΔI) in the inductor (L) is greater than ΔI_{O} .

The current ripple in the inductor (L) can be calculated with Equation 3-4.

EQUATION 3-4:

$$\Delta I = \Delta I_O + \frac{(V_{IN} - V_{OUT}) \times t_{DPDL}}{L} + \frac{V_{OUT} t_{DPDH}}{L}$$

For proper inductor selection, note that the maximum switching frequency occurs at the highest V_{IN} and $V_{OUT} = V_{IN}/2$.

3.8 MOSFET Selection

MOSFET selection is based on the maximum input operating voltage V_{IN} , output current I_{LED} and operating switching frequency. Choose a MOSFET that has a higher breakdown voltage than the maximum operation voltage, low $R_{DS(ON)}$ and low total charge for better efficiency. MOSFET threshold voltage must be adequate when operated at the low end of the input voltage operating range.

3.9 Freewheeling Diode Selection

The forward voltage of the freewheeling diode should be as low as possible for better efficiency. A Schottky diode is a good choice as long as the breakdown voltage is high enough to withstand the maximum operating voltage. The forward current rating of the diode must be at least equal to the maximum LED current.

3.10 LED Current Ripple

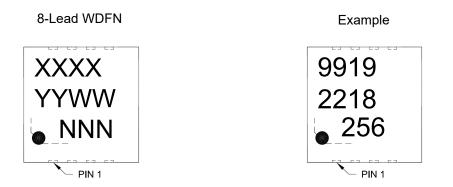
The LED current ripple is equal to the inductor current ripple. In cases when a lower LED current ripple is needed, a capacitor can be placed across the LED terminals.

3.11 PCB Layout Guidelines

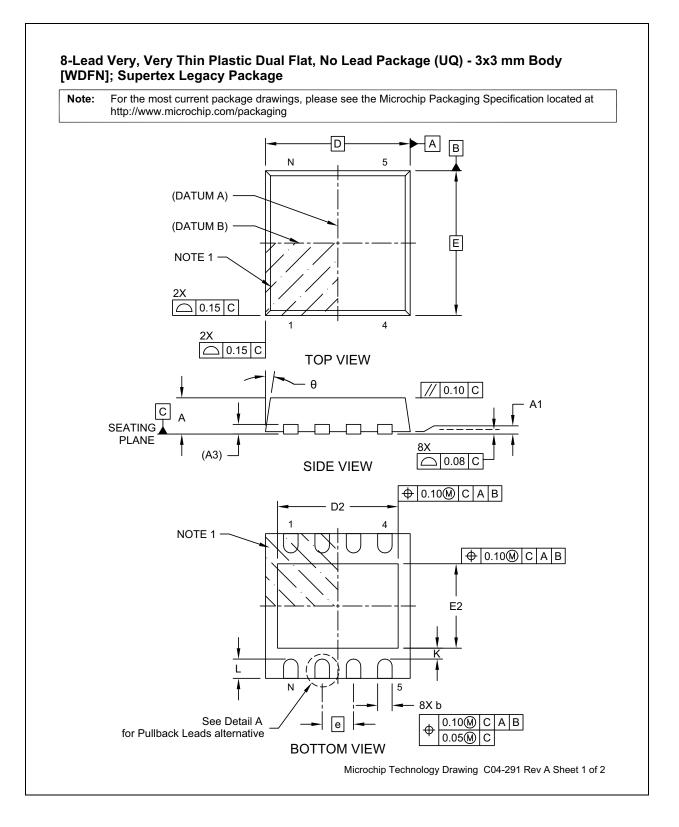
Careful PCB layout is critical to achieving low switching losses and stable operation. Use a multilayer board whenever possible for better noise immunity. Minimize ground noise by connecting high-current ground returns, the input bypass capacitor ground lead and the output filter ground lead to a single point (star ground configuration). The fast *di/dt* loop is composed of the input capacitor CIN, the freewheeling diode and the MOSFET. To minimize noise interaction, this loop area should be as small as possible. Place $\mathsf{R}_{\mathsf{SENSE}}$ as close as possible to the input filter and V_{IN} . For better noise immunity, Kelvin connection is strongly а recommended between CS and R_{SENSE}. Connect the exposed tab of the IC to a large area ground plane for improved power dissipation.

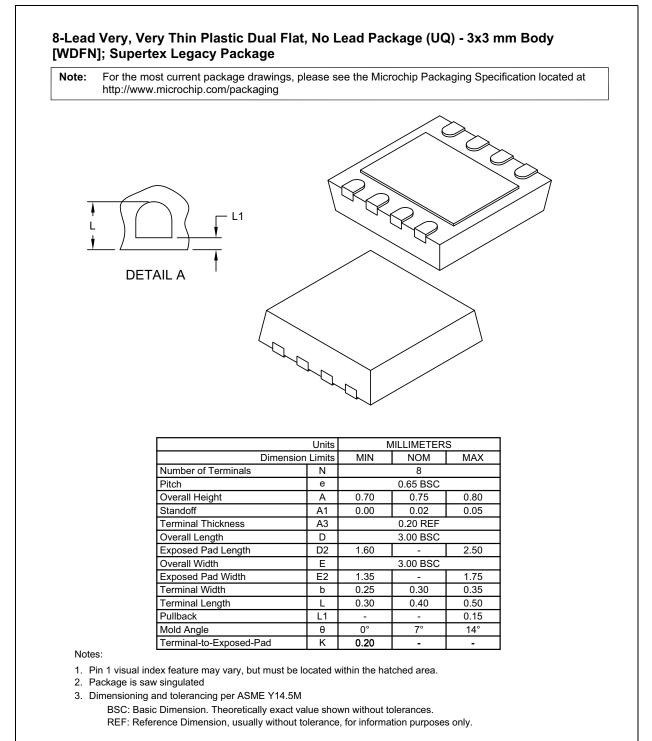
4.0 PACKAGING INFORMATION

4.1 Package Marking Information

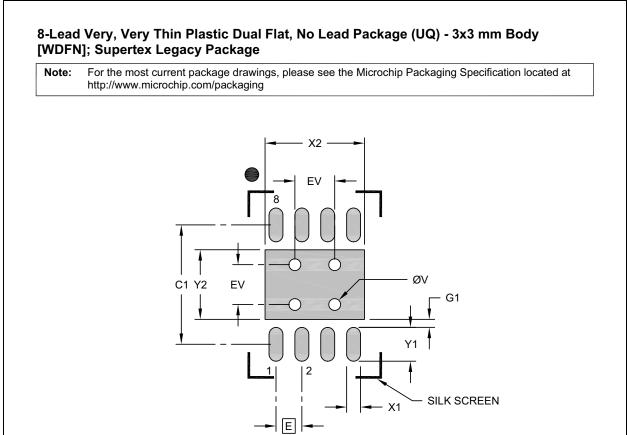


Legend:	XXX Y YY WW NNN @3 *	Product code or customer-specific information Year code (last digit of calendar year) Year code (last 2 digits of calendar year) Week code (week of January 1 is week '01') Alphanumeric traceability code Pb-free JEDEC [®] designator for Matte Tin (Sn) This package is Pb-free. The Pb-free JEDEC designator (e3) can be found on the outer packaging for this package.
	●, ▲, ▼ mark).	Pin one index is identified by a dot, delta up, or delta down (triangle
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Microchip Technology Drawing C04-291A Sheet 2 of 2



RECOMMENDED LAND PATTERN

	MILLIMETERS				
Dimensior	n Limits	MIN	NOM	MAX	
Contact Pitch	E	0.65 BSC			
Optional Center Pad Width	X2			2.50	
Optional Center Pad Length	Y2			1.75	
Contact Pad Spacing	C1		3.00		
Contact Pad Width (X8)	X1			0.35	
Contact Pad Length (X8)	Y1			0.85	
Contact Pad to Center Pad (X8)	G1	0.20			
Thermal Via Diameter	V		0.33		
Thermal Via Pitch	EV				

Notes:

- 1. Dimensioning and tolerancing per ASME Y14.5M
 - BSC: Basic Dimension. Theoretically exact value shown without tolerances.
- 2. For best soldering results, thermal vias, if used, should be filled or tented to avoid solder loss during reflow process

Microchip Technology Drawing C04-2291 Rev A

APPENDIX A: REVISION HISTORY

Revision B (July 2022)

- Added information about the automotive qualification status of the device in **Section "Features"**.
- Updated Section 4.1 "Package Marking Information".
- Modified package type from 8-Lead DFN to 8-Lead WDFN.
- Updated Section "Product Identification System", with Automotive Qualified devices.
- Minor text and format changes throughout.

Revision A (October 2016)

- Converted Supertex Doc# DSFP-AT9919 to Microchip DS20005595A.
- Changed packaging quantity of 8-lead DFN from 3000/Reel to 3300/Reel.
- Made minor text changes throughout the document.

PRODUCT IDENTIFICATION SYSTEM

To order or obtain information, e.g., on pricing or delivery, contact your local Microchip representative or sales office.

PART NO.	XX	-X	XXX	Exar	mple:		
Device	Package Options	T Environmental	Qualification	a) b)	АТ9919К	(7-G: (7-GVAO:	Hysteretic Buck High-Brightness LED Driver with High-Side Current Sensing, 8-Lead (3x3) WDFN Package, 3300/Reel Hysteretic Buck High-Brightness
Device:	AT9919 =	Hysteretic Buck Hig Driver with High-Sid	gh-Brightness LED de Current Sensing	5)	7100101		LED Driver with High-Side Current Sensing, 8-Lead (3x3) WDFN Pack-age, Automotive Qualified, 3300/Reel
Package:	K7 =	8-Lead (3x3) WDFI	N				
Environmental:	G =	Lead (Pb)-free/Rol	HS-compliant Package				
Qualification:	<blank> = VAO =</blank>	Standard Part Automotive AEC-Q	100 Qualified	N	ote 1:	catalog p is used printed o your Mic	d Reel identifier only appears in the nart number description. This identifier for ordering purposes and is not on the device package. Check with rochip Sales Office for package ty with the Tape and Reel option.

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